SGC8598-100A-R

X-band Internally Matched GaN-HEMT

■ Features

• High Output Power: P_{sat}=51.0dBm (Typ.)

• High Gain: G_p=10.0dB (Typ.)

High Power Added Efficiency: PAE=40% (Typ.)

· Broad Band: 8.5 to 9.8GHz

• Impedance Matched Zin/Zout = 50ohm

· Hermetically Sealed Package

Description

The SGC8598-100A-R is a high power GaN-HEMT that is internally matched for X-band radar bands to provide optimum power and gain in a 50ohm system.



ABSOLUTE MAXIMUM RATING (Case Temperature $T_c=25 \text{ deg.C}$)

Item	Symbol	Rating	Unit
Drain-Source Voltage	V _{DS}	55	V
Gate-Source Voltage	V _{GS}	-15	V
Storage Temperature	T _{stg}	-55 to +125	deg.C
Channel Temperature	T _{ch}	+250	deg.C

RECOMMENDED OPERATING CONDITION

Item	Symbol	Condition	Limit	Unit	
Drain-Source Voltage	V_{DS}		<=50	V	
Forward Gate Current	I_{GF}	Rg=100ohm	<=6.0	mA	
Reverse Gate Current	I_{GR}	Rg=100ohm	>=-4.5	mA	
Channel Temperature	T _{ch}		<+200	deg.C	

ELECTRICAL CHARACTERISTICS (Case Temperature T_c=25 deg.C)

Item	Symbol Condition	Limit			Unit	
	Syllibol	Condition	Min.	Тур.	Max.	Unit
Pinch-off Voltage	V_P	V_{DS} =50V, I_{DS} =6.5mA	-	-4.5	-	V
Frequency Range	Freq.		8.5	-	9.8	GHz
Output Power at Pin=41dBm	P_{sat}	V - = 50V-tvp	50.0	51.0	-	dBm
Power Gain at Pout=50dBm	G_P	V _{DS} =50V-typ.	9.0	10.0	-	dB
Drain Current at Pin=41dBm	I_{DSR}	$I_{DS(DC)}=0.33A-typ.$	-	5.7	7.4	Α
Power Added Efficiency at Pin=41dBm	PAE	Pulse Width=100µsec. Duty=10%	-	40	-	%
Gain Flatness	ΔG		-	1.6	-	dB
Thermal Resistance	R _{th}	Channel to Case (P _{diss} =100W, CW)	-	1.4	1.8	deg.C/W

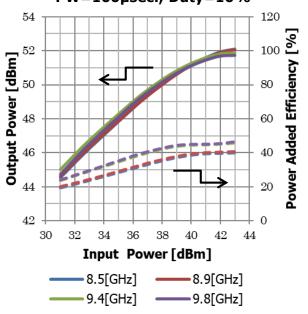
CASE STYLE	IK	
RoHS Compliance	YES	
ESD	Class 2	2000V to <4000V

Note: Based on ANSI/ESDA/JEDEC JS-001-2012(C=100pF, R=1.5kohm)

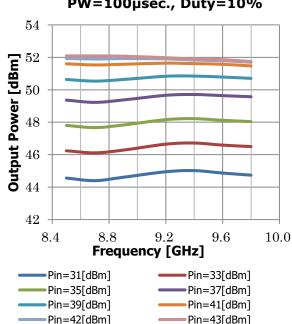


RF Characteristics

Output Power & Power Added Efficiency vs. Input Power V_{DS} =50V, $I_{DS(DC)}$ =0.33A PW=100 μ sec., Duty=10%

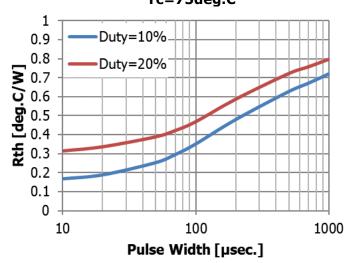


Output Power vs. Frequency V_{DS}=50V, I_{DS(DC)}=0.33A PW=100µsec., Duty=10%

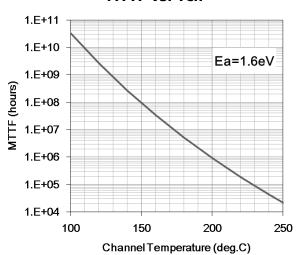


• Thermal Characteristics In Pulsed Operation

Rth vs. Pulse Width Tc=75deg.C



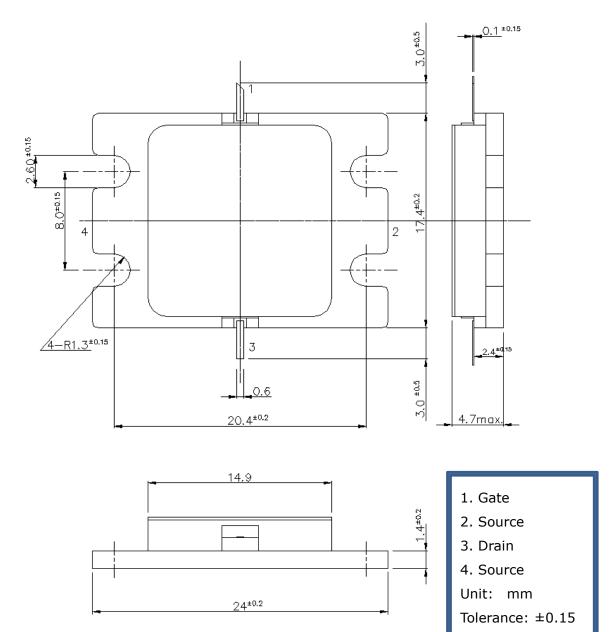
MTTF vs. Tch





• Package Outline

Case Style: IK





For Safety, Observe the Following Procedures Environmental Management

- Do not put this product into the mouth.
- Do not alter the form of this product into a gas, powder, or liquid through burning, crushing, or chemical processing as these by-products are dangerous to the human body if inhaled, ingested, or swallowed.
- Respect all applicable laws of the country when discarding this product.
 This product must be disposed in accordance with methods specified by applicable hazardous waste procedures.

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